onsemi

Silicon Photomultipliers (SiPM), High PDE and Timing Resolution Sensors in a TSV Package

J-Series SiPM Sensors

onsemi's J-Series low-light sensors feature a high PDE (photon detection efficiency) that is achieved using a high-volume, P-on-N silicon foundry process. The J-Series sensors incorporate major improvements in the transit time spread which results in a significant improvement in the timing performance of the sensor. J-Series sensors are available in different sizes (3 mm, 4 mm and 6 mm) and use a TSV (Through Silicon Via) process to create a package with minimal deadspace, that is compatible with industry standard lead-free, reflow soldering processes.

The J-Series Silicon Photomultipliers (SiPM) combine high performance with the practical advantages of solid-state technology: low operating voltage, excellent temperature stability, robustness, compactness, output uniformity, and low cost. For more information on the J-Series sensors please refer to the <u>website</u>.



ORDERING INFORMATION

See detailed ordering and shipping information on page 11 of this data sheet.

| Table 1. GENERAL PARAMETERS | | | | |
|-----------------------------|--|--|--|--|
| Parameter (Note 1) | | | | |

| Parameter (Note 1) | Minimum | Typical | Maximum | Unit |
|-------------------------------------|---------|---------|---------|-------|
| Breakdown Voltage (Vbr) (Note 2) | 24.2 | | 24.7 | V |
| Overvoltage (OV) | 1 | | 6 | V |
| Operating Voltage (Vop = Vbr + OV)) | 25.2 | | 30.7 | V |
| Spectral Range (Note 3) | 200 | | 900 | nm |
| Peak PDE Wavelength (λp) | | 420 | | nm |
| Temperature dependence of Vbr | | 21.5 | | mV/°C |

1. All measurements made at 21°C unless otherwise stated.

2. The breakdown voltage (Vbr) is defined as the value of the voltage intercept of a straight line fit to a plot of √I vs V, where I is the current and V is the bias voltage.

3. The range where PDE > 2.0% at Vbr + 6.0 V.

Table 2. PHYSICAL PARAMETERS

| | 3 mm | 4 mm | 6 mm |
|-----------------------|--------------------------------|------------------------------|-------------------------------|
| Parameter | 30020, 30035 | 40035 | 60035 |
| Active Area | $3.07 	imes 3.07 \text{ mm}^2$ | $3.93\times3.93~\text{mm}^2$ | $6.07	imes 6.07\ \text{mm}^2$ |
| No. of Microcells | 30020: 14,410 30035: 5,676 | 40035: 9,260 | 60035: 22,292 |
| Microcell Fill Factor | 30020: 62% 30035: 75% | 40035: 75% | 60035: 75% |

Table 3. PERFORMANCE PARAMETERS

| | 30 | 30035 40035 | | 60035 | | Unit | |
|---|------------------|-----------------------|------------------|------------------|---------------------|------------------|---------------------|
| | Overvoltage | | | | | | |
| Parameter (Note 4) | +2.5 V | +6 V | +2.5 V | +6 V | +2.5 V | +6 V | Unit |
| PDE (Note 5) | 38 | 50 | 38 | 50 | 38 | 50 | % |
| Dark Count Rate | 50 | 150 | 50 | 150 | 50 | 150 | kHz/mm ² |
| Gain (anode-cathode) | $2.9	imes10^{6}$ | $6.3	imes10^{6}$ | $2.9	imes10^{6}$ | $6.3	imes10^{6}$ | $2.9	imes10^{6}$ | $6.3	imes10^{6}$ | |
| Dark Current – typical | 0.23 | 1.9 | 0.35 | 3.0 | 0.9 | 7.5 | μΑ |
| Dark Current – maximum | 0.31 | 3.00 | 0.45 | 4.0 | 1.25 | 12.0 | |
| Rise Time (Note 6) - anode-cathode output | 90 | 110 | 90 | 110 | 180 | 250 | ps |
| Microcell Recharge Time Constant (Note 7) | 4 | 5 | 4 | 8 | 5 | 60 | ns |
| Capacitance (Note 8) (anode output) | 10 | 070 | 18 | 00 | 41 | 40 | pF |
| Capacitance (Note 8) (fast output) | 4 | 0 | 7 | 70 160 | | 60 | pF |
| Fast Output Pulse Width (FWHM) | 1 | 1.5 | | 1.7 | | 3.0 | |
| Crosstalk | 8 | 25 | 8 | 25 | 8 | 25 | % |
| Afterpulsing | 0.75 | 5.0 | 0.75 | 5.0 | 0.75 | 5.0 | % |
| | 30020 | | | | | | |
| | | | Overv | oltage | | | |
| Parameter (Note 4) | +2.5 V | | | +5 V | | | Unit |
| PDE (Note 5) | 30 | | | 38 | | | % |
| Dark Count Rate | 50 | | | 125 | | | kHz/mm ² |
| Gain (anode-cathode) | | 1.0 × 10 ⁶ | | | 1.9×10 ⁶ | | |
| Dark Current – typical | 0.1 | | | 0.45 | | | μΑ |
| Dark Current – maximum | 0.2 | | 0.72 | | | | |
| Rise Time (Note 6) - anode-cathode output | 130 | | | 160 | | | ps |
| Microcell Recharge Time Constant (Note 7) | 15 | | | | ns | | |
| Capacitance (Note 8) (anode output) | 1040 | | | | pF | | |
| Capacitance (Note 8) (fast output) | 50 | | | 50 | | | pF |
| Fast Output Pulse Width (FWHM) | 1.4 | | | | ns | | |
| Crosstalk | 2.5 | | | 7.5 | | | % |
| Afterpulsing | 0.75 | | | 5.0 | | | % |

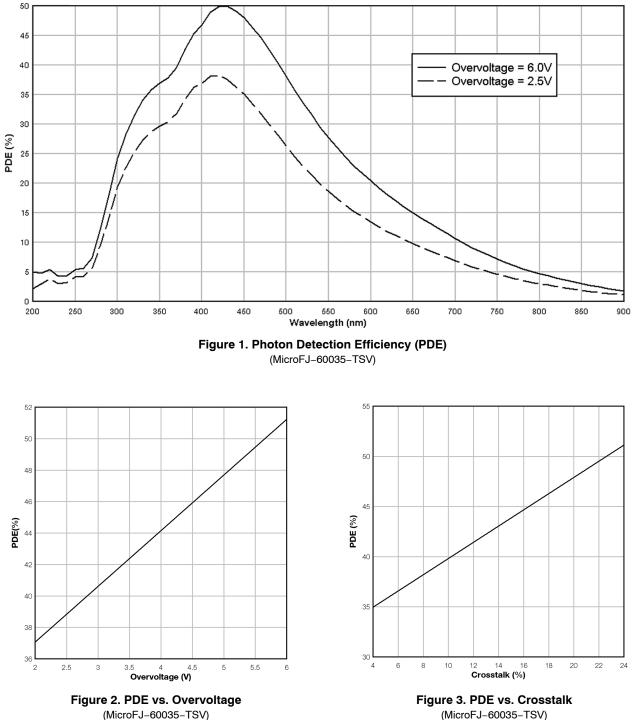
4. All measurements made at 21°C unless otherwise stated. 5. PDE does not contain afterpulsing or crosstalk, and is quoted at the peak wavelength (λ_p). 6. Measured as time to go from 10% to 90% of the peak amplitude and measured over a 1 Ω series output resistor. 7. RC charging time constant of the microcell (τ). 8. Capacitance values are for the complete TSV package.

Table 4. TVS PACKAGE SPECIFICS

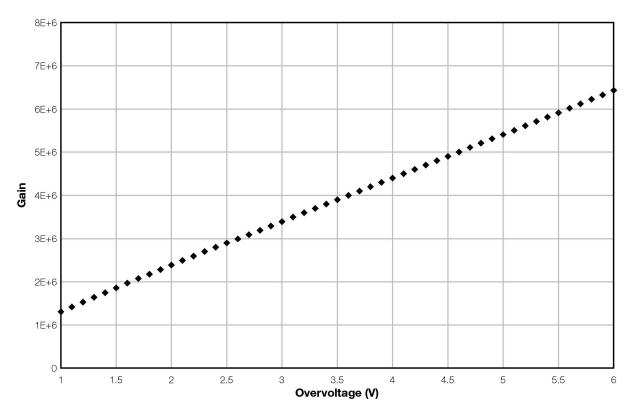
| | | 3 mm | 4 mm | 6 mm |
|---|-------------|------------------------------|-------------------------|-------------------------------|
| | | 30020, 30035 | 40035 | 60035 |
| Package Dimensions | | $3.16\times3.16~\text{mm}^2$ | $4.00\times 4.00\ mm^2$ | $6.13	imes 6.13\ \text{mm}^2$ |
| Recommended Operating Temperature Range | | | −40°C − +85°C | • |
| Soldering Conditions | | Reflow Solder | | |
| Cover Material | | Glass | | |
| Cover Refractive Index | | 1.53 @ 436 nm | | |
| Moisture Sensitivity Level | Tape & reel | MSL3* | | |
| | Cut tape | Cut tape MSL4* | | |
| Maximum Average Current | • | 10 mA 10 mA 15 mA | | |

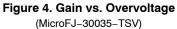
*Please refer to the <u>TSV Handling and Soldering</u> guide for more information on MSL for different delivery options.

PERFORMANCE PLOTS



⁽MicroFJ-60035-TSV)





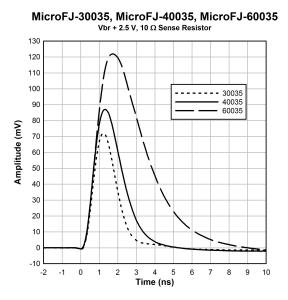


Figure 5. Fast Output Pulse Shape (MicroFJ–30035, MicroFJ–40035, MicroFJ–60035 Vbr + 2.5 V, 10 Ω Sense Resistor)

MicroFJ-30035, MicroFJ-40035, MicroFJ-60035 Vbr + 2.5 V, 10 Ω Series Resistor

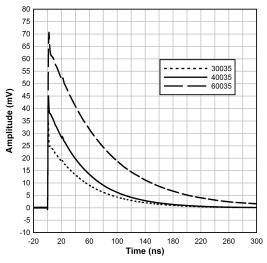


Figure 6. Standard Output Pulse Shape (MicroFJ-30035, MicroFJ-40035, MicroFJ-60035 Vbr + 2.5 V, 10 Ω Sense Resistor)

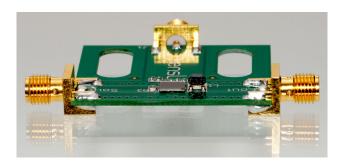
4

EVALUATION BOARD OPTIONS

SMA BIASING BOARD (MicroFJ-SMA-XXXXX)

The MicroFJ–SMA is a printed circuit board (PCB) that can facilitate the evaluation of the J-Series sensors. The board has three female SMA connectors for connecting the bias voltage, the standard output from the anode and the fast output signal. The output signals can be connected directly to a 50 Ω -terminated oscilloscope for viewing. The biasing and output signal tracks are laid out in such a way as to preserve the fast timing characteristics of the sensor.

The MicroFJ–SMA is recommended for users who require a plug-and-play set-up to quickly evaluate J-Series TSV sensors with optimum timing performance. The board also allows the standard output from the anode to be observed at the same time as the fast output. The outputs can be connected directly to the oscilloscope or measurement device, but external preamplification may be required to boost the signal. The table below lists the SMA board connections. The SMA board electrical schematics are available to download in the <u>AND9808/D</u> document.



| MicroFJ-SMA-XXXXX | | | |
|-------------------|-------------------------------|--|--|
| Output | Function | | |
| Vbias | Positive bias input (cathode) | | |
| Fout | Fast output | | |
| Sout | Standard output (anode) | | |

PIN ADAPTER (MicroFJ-SMTPA-XXXXX)

The TSV Pin Adapter board (SMTPA) is a small PCB board that houses the TSV sensor and has through-hole pins to allow its use with standard sockets or probe clips. This product is useful for those needing a quick way to evaluate the TSV package without the need for specialist surface-mount soldering. While this is a 'quick fix' suitable for many evaluations, it should be noted that the timing performance from this board will not be optimized and if the best possible timing performance is required, the MicroFJ–SMA–XXXXX is recommended. The SMTPA

circuit schematic is shown in Figure 8. Please consult the <u>Readout and Biasing Application Note</u> for further information on biasing. The SMTPA board electrical schematics are available to download in the <u>AND9808/D</u>.

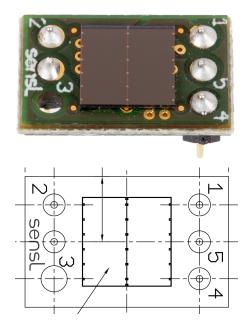


Figure 7. Top View of the SMTPA Board Showing the Pin Numbering

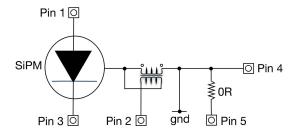


Figure 8. SMTPA Circuit Schematic

| MicroFJ-SMTPA-XXXXX | | | | |
|---------------------|-------------|--|--|--|
| Pin No. | Connection | | | |
| 1 | Anode | | | |
| 2 | Fast output | | | |
| 3 | Cathode | | | |
| 4 | Ground | | | |
| 5 | No connect | | | |

CIRCUIT SCHEMATICS

An SiPM is formed of a large number (hundreds or thousands) of microcells. Each microcell (Figure 9) is an avalanche photodiode with its own quench resistor and a capacitively coupled fast output. These microcells are arranged in a close-packed array with all of the like terminals (e.g. all of the anodes) summed together (Figure 10). The array of microcells can thus be considered as a single photodiode sensor with three terminals: anode, cathode and fast output, as shown in Figure 11.

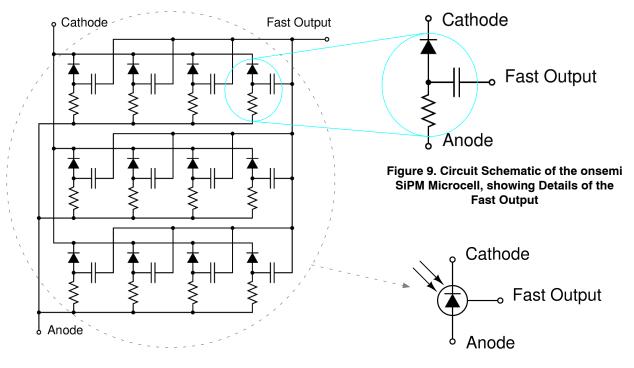


Figure 11. onsemi SiPM Component Symbol



TILING OF THE TSV PACKAGE

For the J-Series, **onsemi** has developed a market-leading, high-performance package using a TSV process. It is a chip-scale package that is compatible with lead-free, reflow soldering processes. The glass cover is ideal for coupling to scintillators or fibre optic elements.

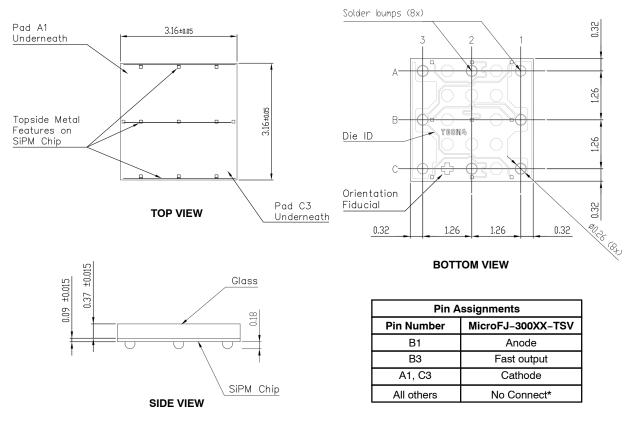
The dead-space between the sensor active area and the edge of the package has been minimized, resulting in a package that can be tiled on 4 sides with high fill-factor.

This allows multiple sensors to be configured into unique layouts for a wide range of custom applications. The distance between sensor packages can be as little as 200 μ m when tiled, but actual alignment and placement tolerances will depend on the accuracy of the user's assembly process. An <u>Application Note</u> is available that gives advice on creating arrays of the TSV sensors.

PACKAGE DIMENSIONS

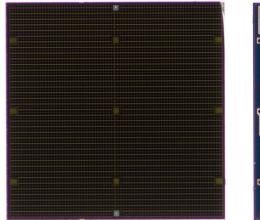
(All Dimensions in mm)

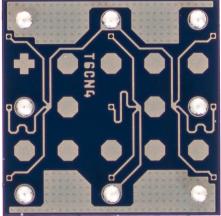
MicroFJ-300XX-TSV



*The 'No Connect' pins are electrically isolated and should be soldered to a ground (or bias) plane to help with heat dissipation.

The MicroFJ-300XX-TSV-A2 CAD, and solder footprint, is available to download here.

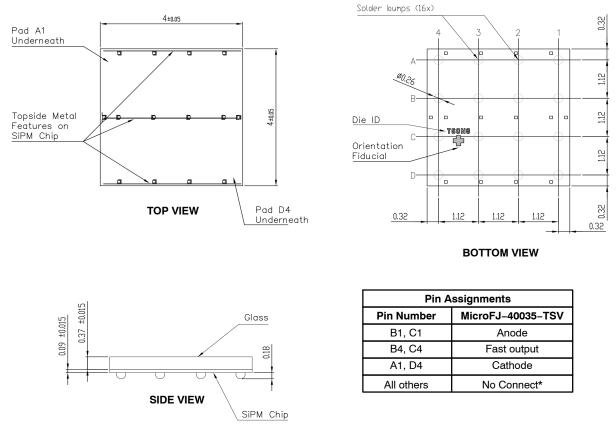




PACKAGE DIMENSIONS

(All Dimensions in mm)

MicroFJ-40035-TSV



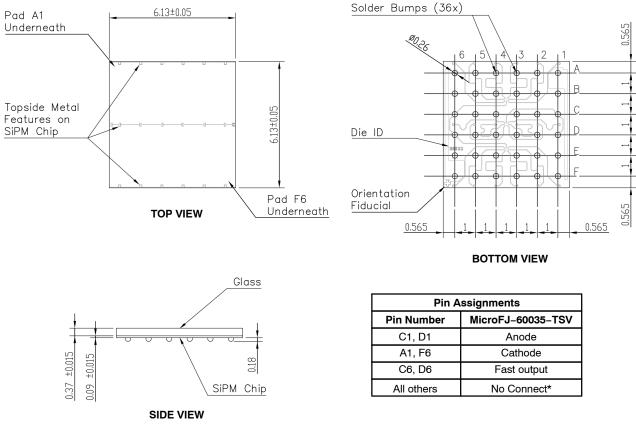
*The 'No Connect' pins are electrically isolated and should be soldered to a ground (or bias) plane to help with heat dissipation.

The MicroFJ-40035-TSV CAD, and solder footprint, is available to download here.

PACKAGE DIMENSIONS

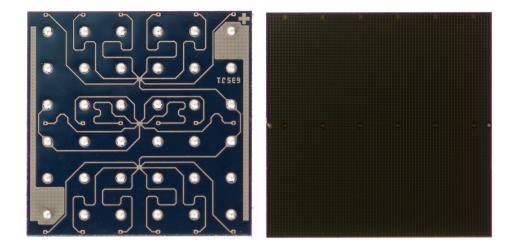
(All Dimensions in mm)

MicroFJ-60035-TSV

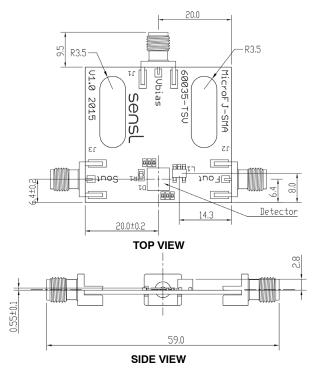


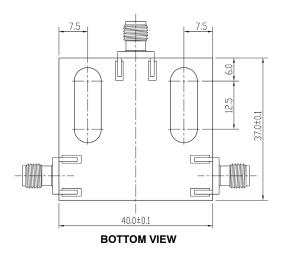
*The 'No Connect' pins are electrically isolated and should be soldered to a ground (or bias) plane to help with heat dissipation.

The MicroFJ-60035-TSV CAD, and solder footprint, is available to download here.

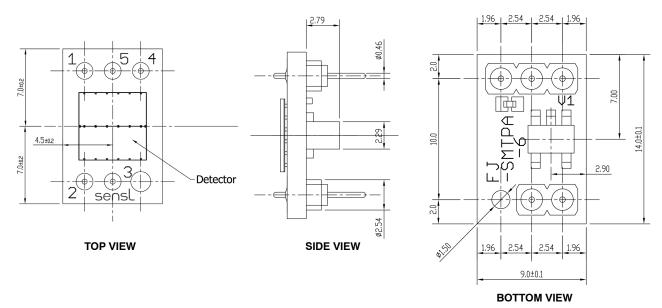


MicroFJ-SMA-60035 Board





The complete CAD for the SMA boards can be downloaded from the website: <u>3 mm</u>, <u>4 mm</u> and <u>6 mm</u> versions.



MicroFJ-SMTPA-60035 Board

The complete CAD for the SMTPA boards can be downloaded from the website: <u>3 mm</u> and <u>6 mm</u> versions.

ORDERING INFORMATION

Table 5. ORDERING INFORMATION

| Product Code | Microcell Size (No. of Microcells) | Sensor Active Area | Description | Delivery Option (Note 9) |
|--------------------------|---------------------------------------|--------------------------|--|--------------------------------|
| 3 mm Sensors | | | | |
| MICROFJ-30020-TSV | 20 μm (14,410) | 3.07 	imes 3.07 mm | 4-side tileable, chip scale package with through-silicon vias (TSV) | TR1, TR |
| MICROFJ-SMA-30020-GEVB | | | TSV sensor mounted onto a PCB with three SMA connectors for bias, standard output and fast output | PK |
| MICROFJ-SMTPA-30020-GEVB | | | TSV sensor mounted onto a pin adapter board | PK |
| MICROFJ-30035-TSV | 35 μm (5,676) | | 4-side tileable, chip scale package with through-silicon vias (TSV) | TR1, TR |
| MICROFJ-SMA-30035-GEVB | | | TSV sensor mounted onto a PCB with three SMA connectors for bias, standard output and fast output | PK |
| MICROFJ-SMTPA-30035-GEVB | | | TSV sensor mounted onto a pin adapter board | PK |
| 1 mm Sensors | | | • | |
| MICROFJ-40035-TSV | 35 μm (9,260) | 3.93	imes 3.93 mm | 4-side tileable, chip scale package with through-silicon vias (TSV) | TR1, TR |
| MICROFJ-SMA-40035-GEVB | | | TSV sensor mounted onto a PCB with three SMA connectors for bias, standard output and fast output. | PK |
| 6 mm Sensors | | | | |
| MICROFJ-60035-TSV | 35 μm (22,292) | 6.07 	imes 6.07 mm | 4-side tileable, chip scale package with through-silicon vias (TSV) | TR1, TR |
| MICROFJ-SMA-60035-GEVB |] | | TSV sensor mounted onto a PCB with three SMA connectors for bias, standard output and fast output | PK |
| MICROFJ-SMTPA-60035-GEVB | | | TSV sensor mounted onto a pin adapter board | PK |

 The two-letter delivery option code should be appended to the order number, e.g.) to receive a MICROFJ-60035-TSV on tape and reel, use MICROFJ-60035-TSV-TR. The codes are as follows:

PK = ESD Package

TR1 = Tape

TR = Tape and Reel

There is a minimum order quantity (MOQ) of 3000 for the tape and reel (TR) option. Quantities less than this are available on tape (-TR1). The TR option is only available in multiples of the MOQ.

SensL is a registered trademark of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Photodiodes category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below :

LTR-526AD OED-SP-7L LTR-536AB LTR-743DBM1-TA 67-21SYGC-S349-TR8 SFH 2200 A01 HFD3081-108-XBA BPW 34 S E9601 SFH 2713 SFH 2703 LTR-546AD BPV23FL BPW 34 FAS BPW 34 FS IG22X250S4I VTD205H VTD205KH VTP1220FBH VTP1232FH VTP4085H SFH 2400 OP913WSL OPF794 PD70-01C/TR7 LTR-536AD VTP8651H VTD206KH VTB1013H BPV23NF OP905 LTR-516AD BPW 34 FS-Z VTD34FH QSB34CGR SFH 2500 FA SFH 213 FA PD15-22C/TR8 VEMD5510C SFH 2200 VEMD5510CF APS5130PD7C-P22 SAH230M SAH230M2 SAH500M2 BP 104 FS BPV22F-AS12 BPW 21 BPW 34 SR-Z BPX 65 HSDL-5400#011